

General Description

The MY7N60D is silicon N-channel Enhanced VDMOSFETS, obtained by the self-aligned planar Technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy.

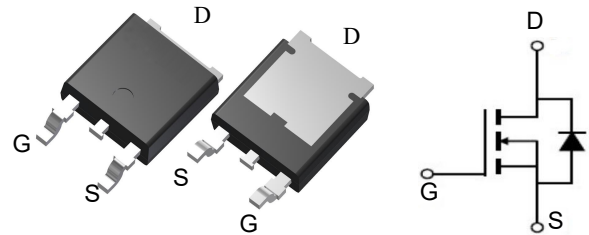


Features

V_{DSS}	600	V
I_D	7	A
P_D ($T_C = 25\text{ }^{\circ}\text{C}$)	39	W
$R_{DS(ON)}$ (at $V_{GS} = 10\text{V}$)	1.2	Ω

Application

- High efficiency switch mode power supplies
- Power factor correction
- Electronic lamp ballast



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY7N60D	TO-252	MY7N60D	2500

Absolute Maximum Ratings ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameters	Ratings	Unit
V_{DSS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage-Continuous	± 30	V
I_D	Drain Current-Continuous (Note 2)	7	A
I_{DM}	Drain Current-Single Plused (Note 1)	28	A
P_D	Power Dissipation (Note 2)	39	W
T_j	Max.Operating junction temperature	150	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_c=25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Symbol	Parameters	Min	Typ	Max	Units	Conditions
Static Characteristics						
B _{VDSS}	Drain-Source Breakdown Voltage (Note 1)	600	--	--	mA	I _D =250μA V _{GS} =0V , T _J =25°C
V _{GS(th)}	Gate Threshold Voltage	2.0	--	4.0	V	V _{DS} =V _{GS} , I _D =250μA
R _{DS(on)}	Drain-Source On-Resistance	--	1.2	1.4	Ω	V _{GS} =10V , I _D =3.5A
I _{GSS}	Gate-Body Leakage Current	--	--	±100	nA	V _{GS} =±30V , V _{DS} =0
I _{DSS}	Zero Gate Voltage Drain Current	--	--	1	μA	V _{DS} =650V , V _{GS} =0
g _{fs}	Forward Transconductance	2.3	--	--	S	V _{DS} =15V, I _D =3.5A
Switching Characteristics						
T _{d (on)}	Turn-On Delay Time	--	48	80	ns	V _{DS} =325V , I _D =7A, R _G =25Ω (Note 2)
T _r	Rise Time	--	135	170	ns	
T _{d (off)}	Turn-Off Delay Time	--	135	175	ns	
T _f	Fall Time	--	280	320	ns	
Q _g	Total Gate Charge	--	30	65	nC	V _{DS} =520, V _{GS} =10V , I _D =7A (Note 2)
Q _{gs}	Gate-Source Charge	--	6.5	--	nC	
Q _{gd}	Gate-Drain Charge	--	13.5	--	nC	
Dynamic Characteristics						
C _{iss}	Input Capacitance	--	1080	1690	pF	V _{DS} =25V , V _{GS} =0, f=1MHz
C _{oss}	Output Capacitance	--	118	200	pF	
C _{rss}	Reverse Transfer Capacitance	--	30	45	pF	
I _S	Continuous Drain-Source Diode Forward Current (Note 2)	--	--	7	A	
V _{SD}	Diode Forward On-Voltage	--	--	1.4	V	I _S =7A , V _{GS} =0
R _{th(j-c)}	Thermal Resistance, Junction to Case	--	--	2.6	°C/W	

Note 1: Repetitive Rating : Pulse width limited by maximum junction temperature

Note 2: Pulse test: $PW \leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

Ratings and Characteristic curves

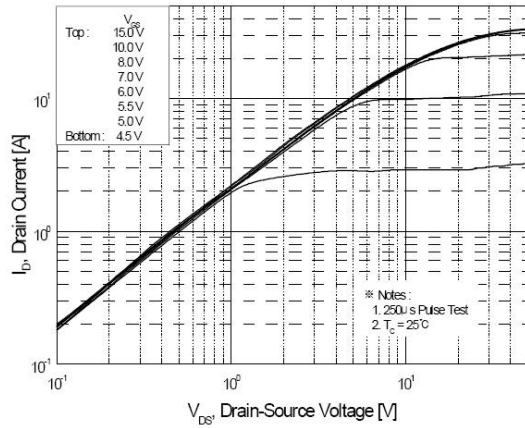


Figure 1. On-Region Characteristics

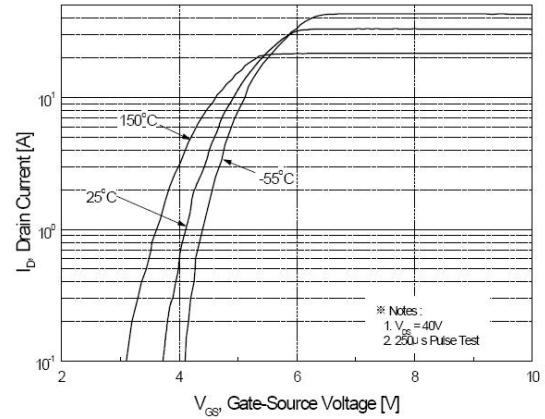


Figure 2. Transfer Characteristics

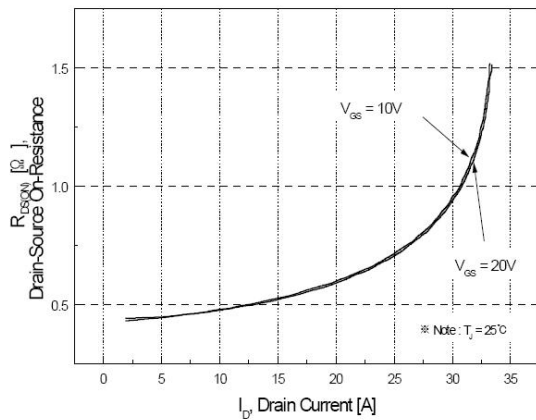


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

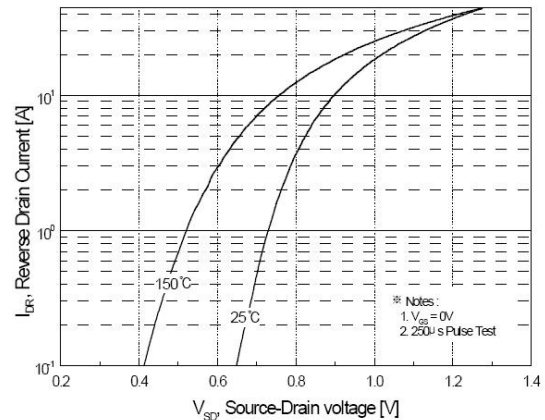


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

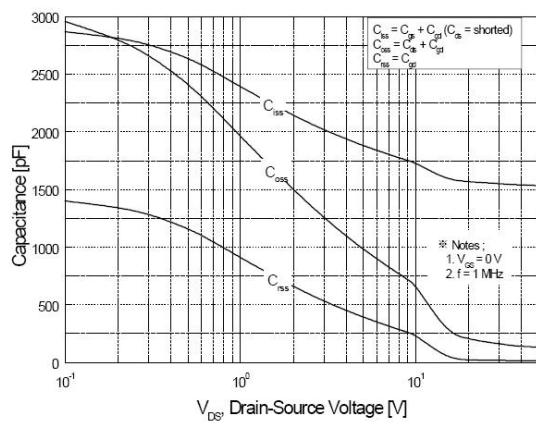


Figure 5. Capacitance Characteristics

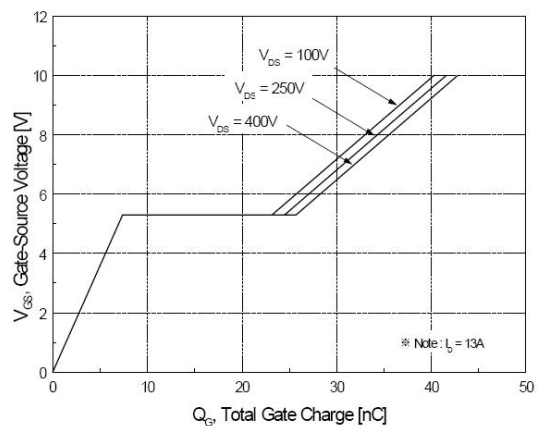


Figure 6. Gate Charge Characteristics

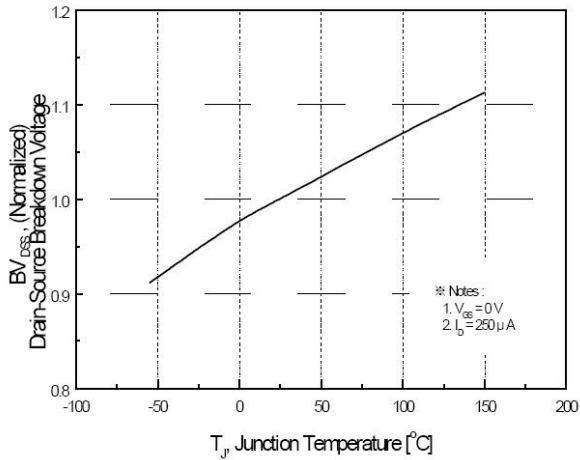


Figure 7. Breakdown Voltage Variation vs Temperature

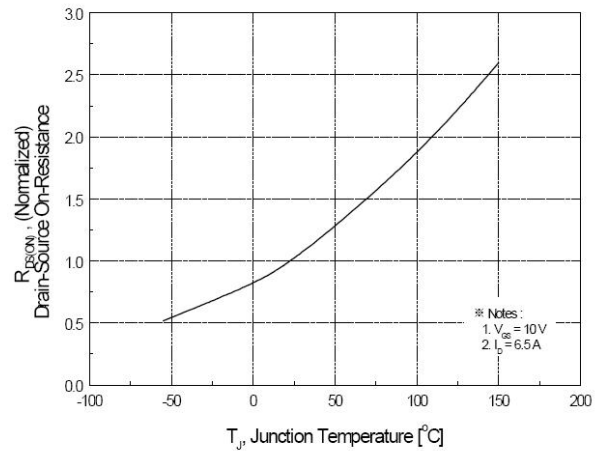


Figure 8. On-Resistance Variation vs Temperature

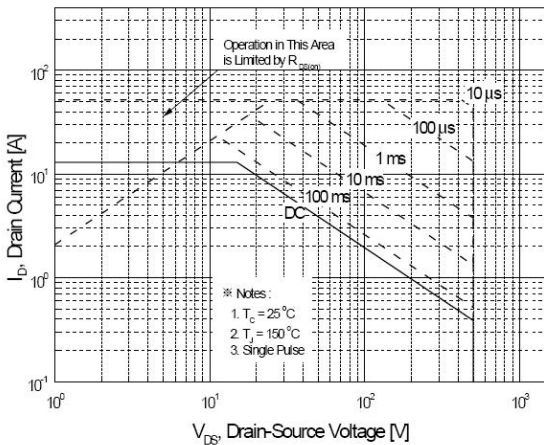


Figure 9. Maximum Safe Operating Area

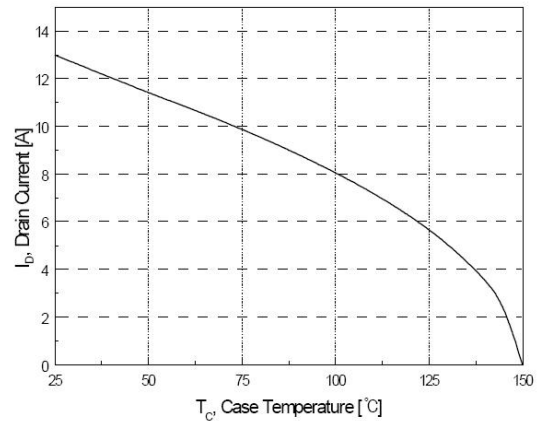


Figure 10. Maximum Drain Current vs Case Temperature

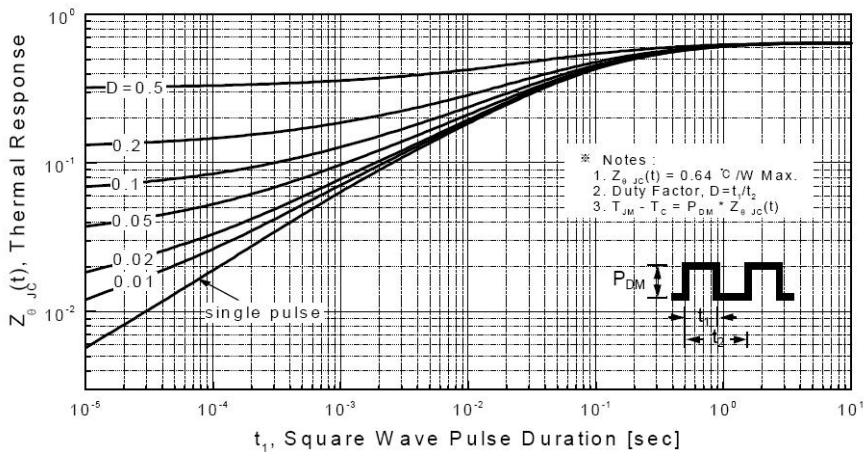


Figure 11. Transient Thermal Response Curve

Fig 12. Gate Charge Test Circuit & Waveform

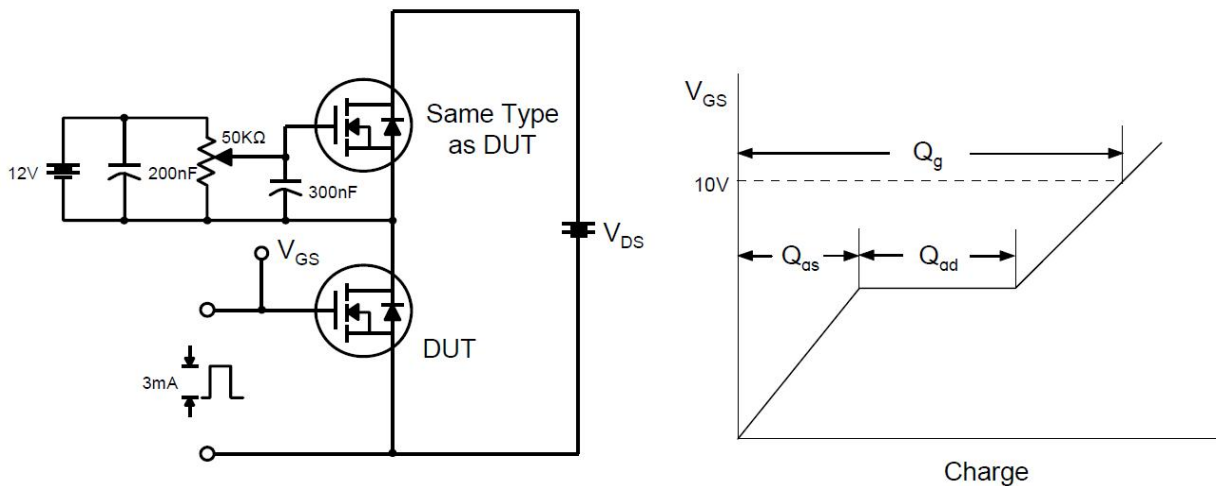


Fig 13. Resistive Switching Test Circuit & Waveforms

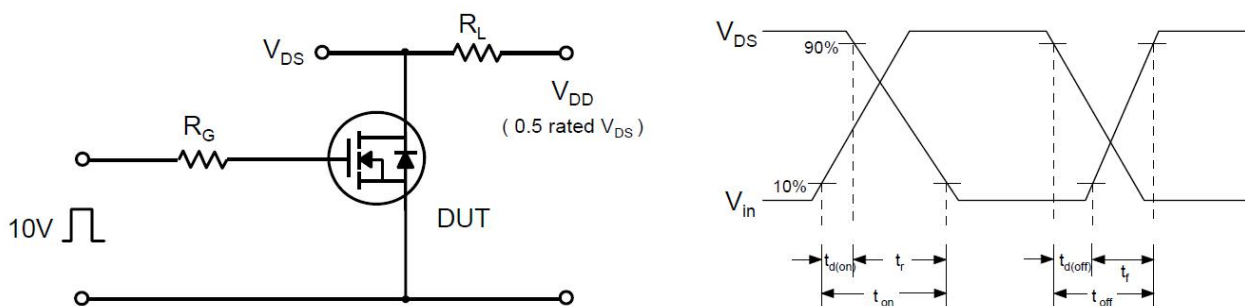


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

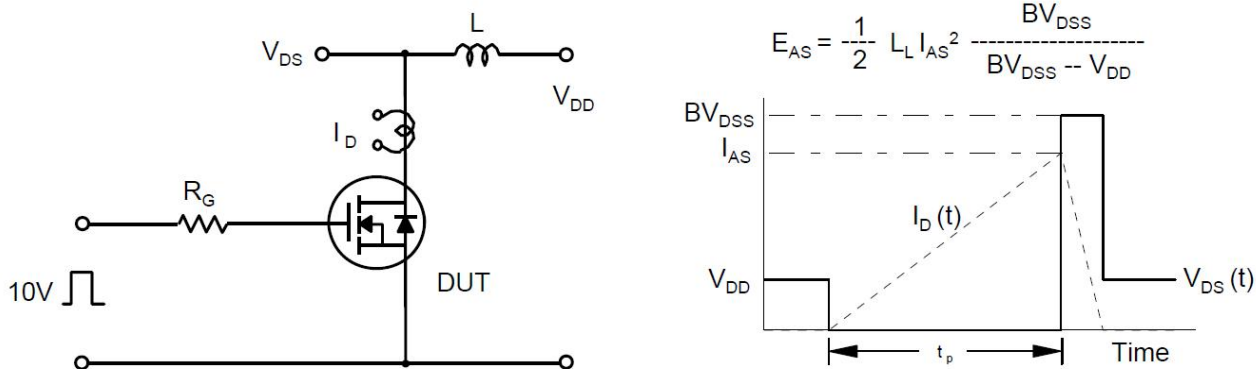
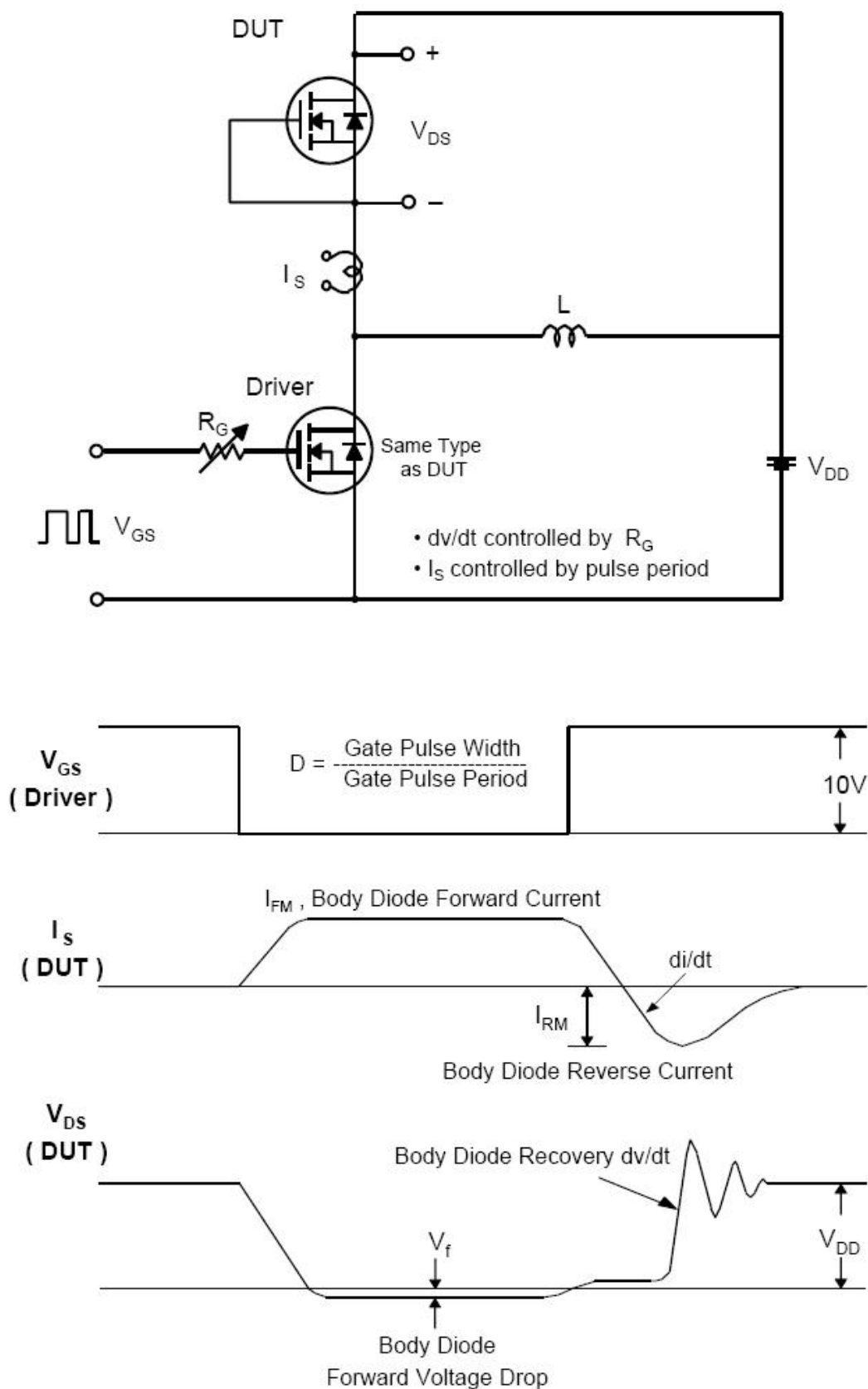
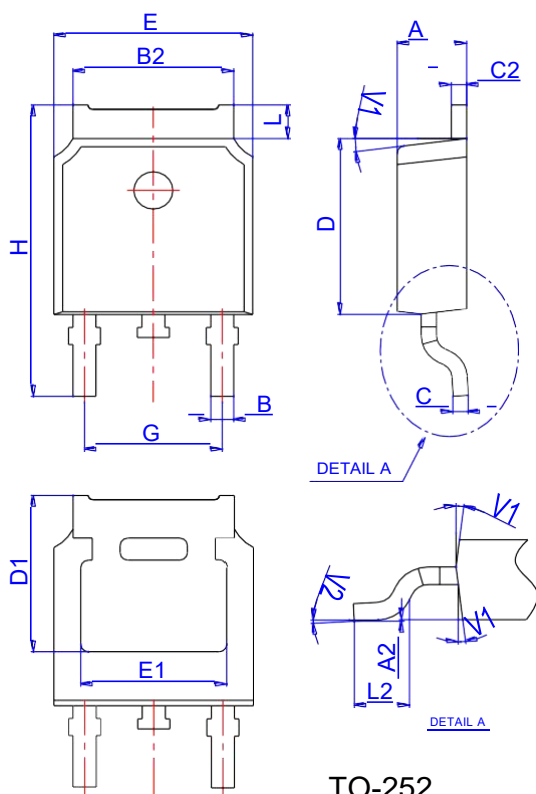


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

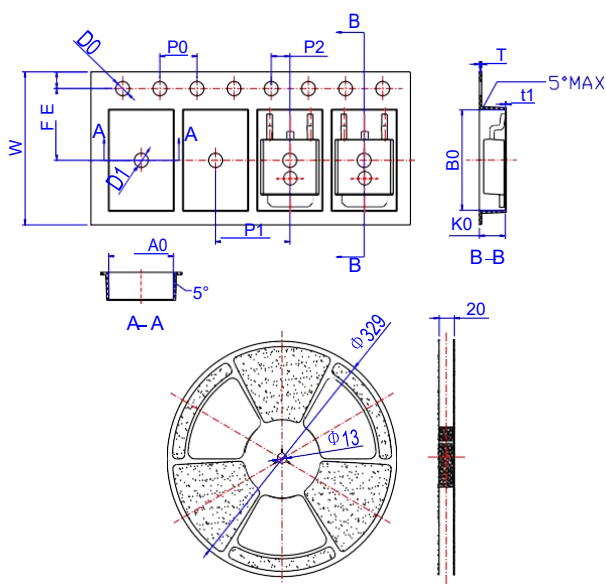


Package Mechanical Data-TO-252-JQ Single



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Specification-TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583